MGA-30689

40MHz - 3000MHz

Flat Gain High Linearity Gain Block

Data Sheet

Description

Avago Technologies' MGA-30689 is a flat gain, high linearity, low noise, 22dBm Gain Block with good OIP3 achieved through the use of Avago Technologies' proprietary 0.25um GaAs Enhancement-mode pHEMT process.

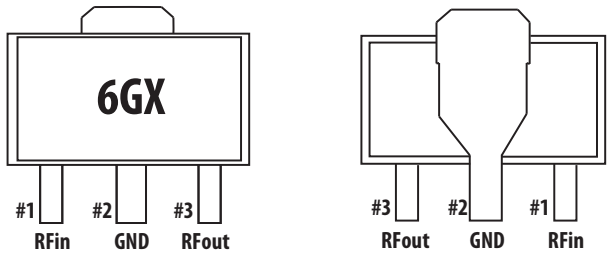
The device required simple dc biasing components to achieve wide bandwidth performance. The temperature compensated internal bias circuit provides stable current over temperature and process threshold voltage variation.

The MGA-30689 is housed inside a standard SOT89 package (4.5 x 4.1 x 1.5 mm).

Applications

- IF amplifier, RF driver amplifier
- General purpose gain block

Component Image



Notes:
Package marking provides orientation and identification
"6G" = Device Code
"X" = Month of manufacture

Features

- Flat Gain 14dB +/-0.5dB, 40MHz to 2600MHz
- High linearity
- Built in temperature compensated internal bias circuitry
- No RF matching components required
- GaAs E-pHEMT Technology[1]
- Standard SOT89 package
- Single, Fixed 5V supply
- Excellent uniformity in product specifications
- MSL-2 and Lead-free halogen free
- High MTTF for base station application

Specifications

- 900MHz; 5V, 104mA (typical)
  - 14.3 dB Gain
  - 43 dBm Output IP3
  - 3.0 dB Noise Figure
  - 22.3 dBm Output Power at 1dB gain compression
- 1950MHz, 5V, 104mA (typical)
  - 14.6 dB Gain
  - 40 dBm Output IP3
  - 3.3 dB Noise Figure
  - 22.5 dBm Output Power at 1dB gain compression

Note:
1. Enhancement mode technology employs positive gate voltage, thereby eliminating the need of negative gate voltage associated with conventional depletion mode devices.



Attention: Observe precautions for handling electrostatic sensitive devices.
ESD Machine Model = 75 V
ESD Human Body Model = 450 V
Refer to Avago Application Note A004R: Electrostatic Discharge, Damage and Control.

Absolute Maximum Rating [2] T_A=25°C

Symbol	Parameter	Units	Absolute Max.
$V_{dd,max}$	Device Voltage, RF output to ground	V	5.5
$P_{in,max}$	CW RF Input Power	dBm	20
P_{diss}	Total Power Dissipation [4]	W	0.75
$T_{j,max}$	Junction Temperature	°C	150
T_{STG}	Storage Temperature	°C	-65 to 150

Thermal Resistance [3] θ_{jc} = 53.5°C/W (Vdd = 5V, Ids = 100mA, Tc = 85°C)

Notes:
2. Operation of this device in excess of any of these limits may cause permanent damage.
3. Thermal resistance measured using Infrared measurement technique.
4. This is limited by maximum Vdd and Ids. Derate 18.7 mW/°C for Tc>110°C.

Product Consistency Distribution Charts[5, 6]

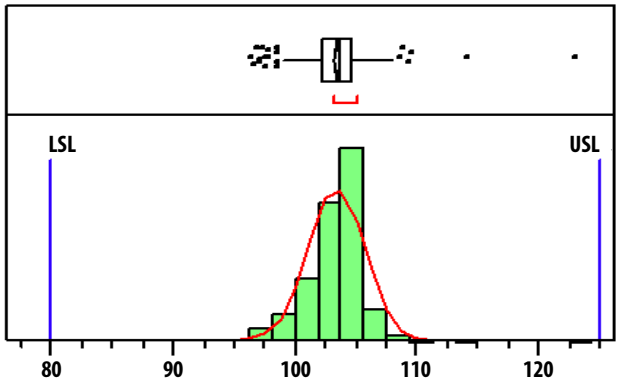


Figure 1. Ids, LSL=80mA , nominal=104mA, USL=125mA

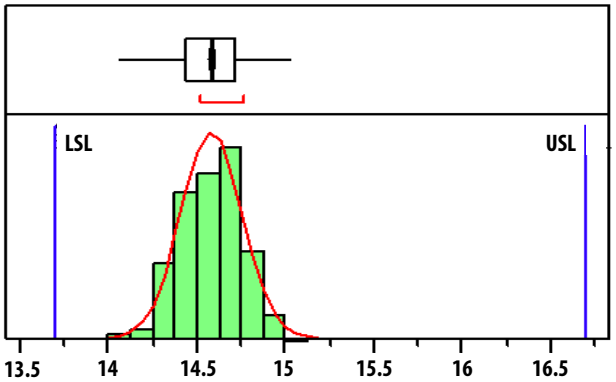


Figure 2. Gain, LSL=13.7dB, nominal=14.6dB, USL=16.7dB

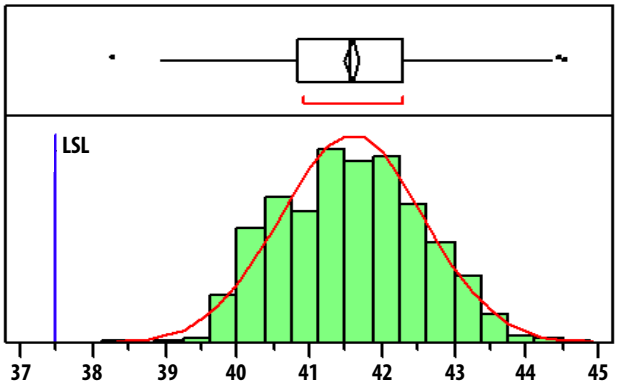


Figure 3. OIP3, LSL=37.5dBm, nominal=41.5dBm

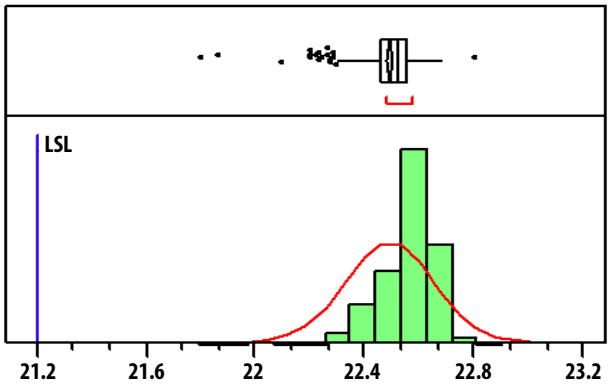


Figure 4. P1dB, LSL=21.2dBm, nominal=22.5dBm

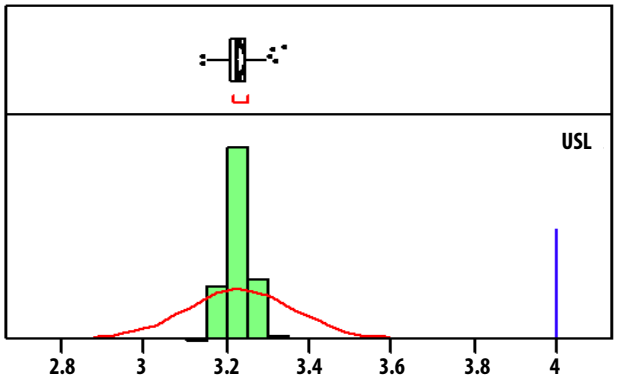


Figure 5. NF, nominal=3.23dB, USL=4dB

Notes:
5. Distribution data sample size is 500 samples taken from 3 different wafer lots and 6 different wafers. Future wafers allocated to this product may have nominal values anywhere between the upper and lower limits.
6. Measurements were made on a characterization test board, which represents a trade-off between optimal OIP3, gain and P1dB. Circuit trace losses have not been de-embedded from measurements above.

Electrical Specifications [7]

T_A = 25°C, Vdd =5V

Symbol	Parameter and Test Condition	Frequency	Units	Min.	Typ.	Max.
Ids	Quiescent current	N/A	mA	80	104	125
Gain	Gain	40MHz	dB		14.8	
		900MHz			14.3	
		1950MHz		13.7	14.6	16.7
OIP3 [8]	Output Third Order Intercept Point	40MHz	dBm		40	
		900MHz			43	
		1950MHz		37.5	40	–
NF	Noise Figure	40MHz	dB		2.9	
		900MHz			3.0	
		1950MHz		–	3.3	4
S11	Input Return Loss, 50Ω source	40MHz	dB		-13	
		900MHz			-12	
		1950MHz			-15	
S22	Output Return Loss, 50Ω load	40MHz	dB		-18	
		900MHz			-15	
		1950MHz			-12	
S12	Reverse Isolation	40MHz	dB		-20	
		900MHz			-22	
		1950MHz			-25	
OP1dB	Output Power at 1dB Gain Compression	40MHz	dBm		21.8	
		900MHz			22.4	
		1950MHz		21.2	22.5	–

Notes:

7. Measurements obtained using demo board described in Figure 30 and 31. 40MHz data was taken with 40MHz – 2GHz Application Test Circuit, 900MHz data with 0.2GHz – 3GHz Application Test Circuit and 1.95GHz data with 1.5GHz – 2.6GHz Application Test Circuit respectively.
8. OIP3 test condition: $F_{RF1} - F_{RF2}$ = 10MHz with input power of -15dBm per tone measured at worse side band.
9. Use proper bias, heat sink and de-rating to ensure maximum channel temperature is not exceeded. See absolute maximum ratings and application note (if applicable) for more details.

Typical Performance (40MHz – 2GHz)

TA = +25°C, Vdd = 5V, Input Signal = CW. Application Test Circuit is shown in Figure 30 and Table 1.

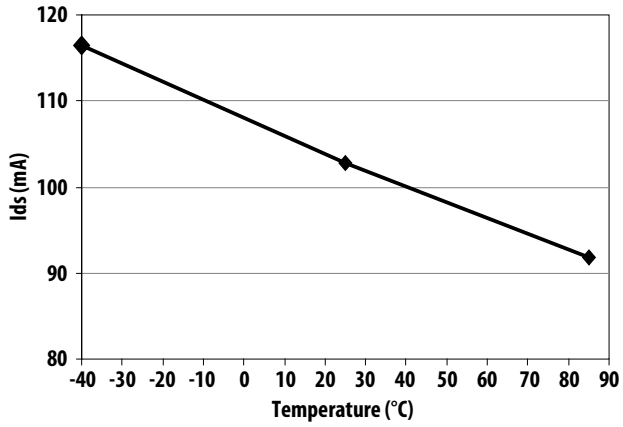


Figure 6. Ids over Temperature

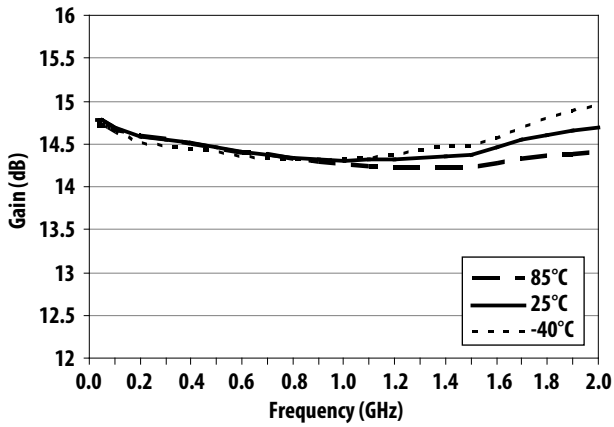


Figure 7. Gain over Frequency and Temperature

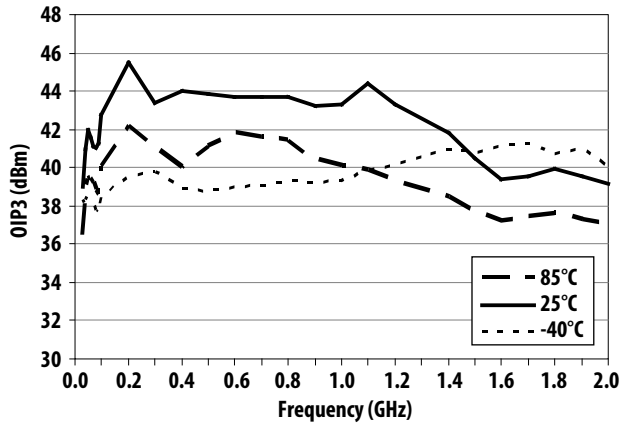


Figure 8. OIP3 over Frequency and Temperature

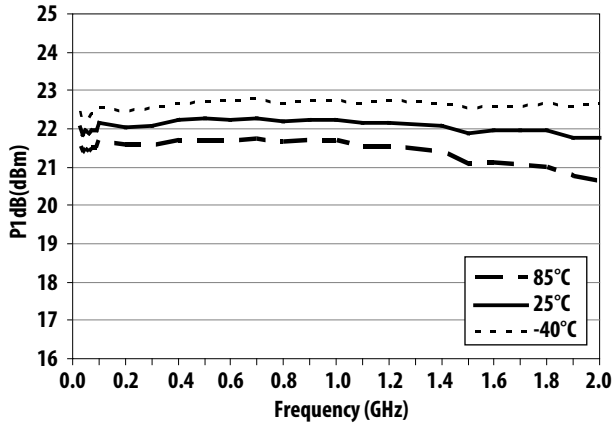


Figure 9. P1dB over Frequency and Temperature

Typical Performance (40MHz – 2GHz)

TA = +25°C, Vdd = 5V, Input Signal = CW. Application Test Circuit is shown in Figure 30 and Table 1.

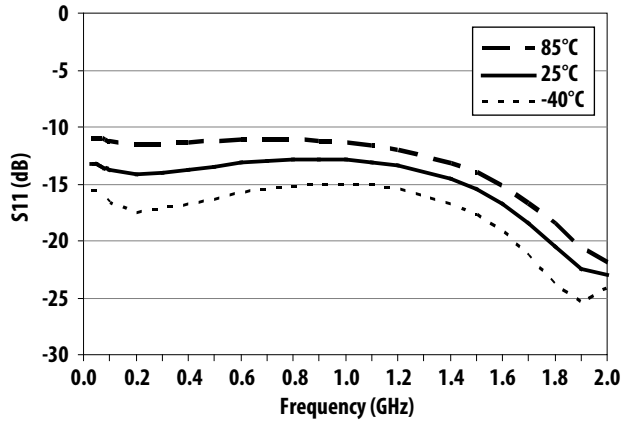


Figure 10. S11 over Frequency and Temperature

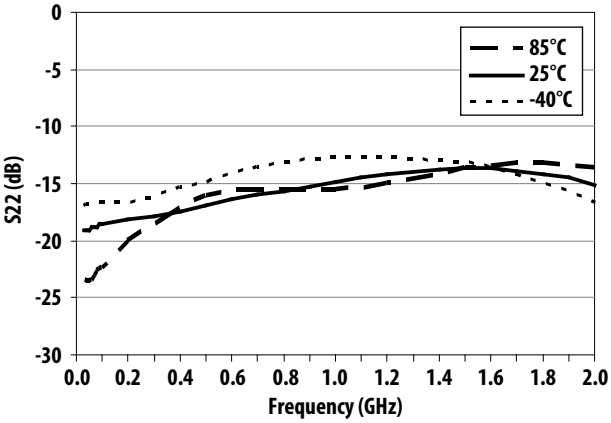


Figure 11. S22 over Frequency and Temperature

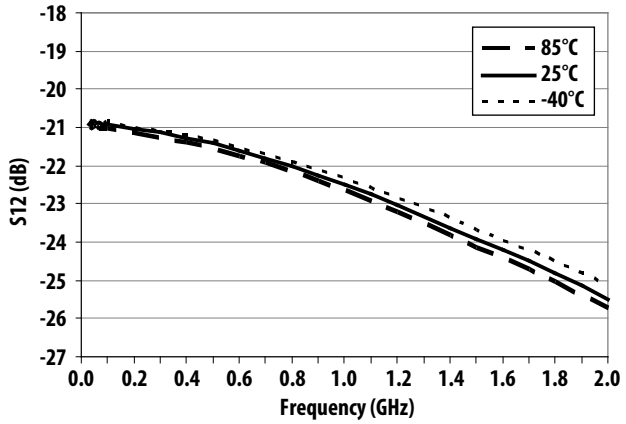


Figure 12. S12 over Frequency and Temperature

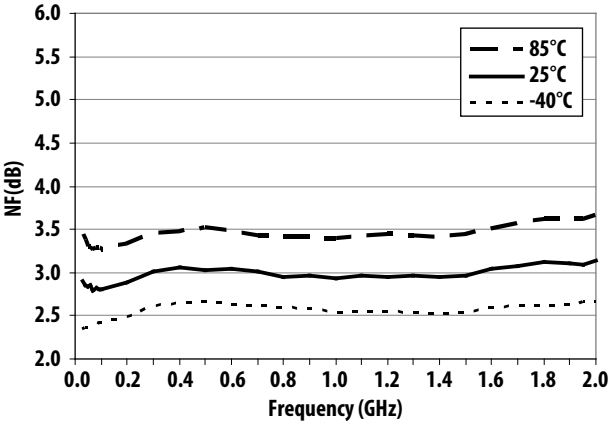


Figure 13. Noise Figure over Frequency and Temperature

Typical Performance (0.2GHz – 3GHz)

TA = +25°C, Vdd = 5V, Input Signal = CW. Application Test Circuit is shown in Figure 30 and Table 2.

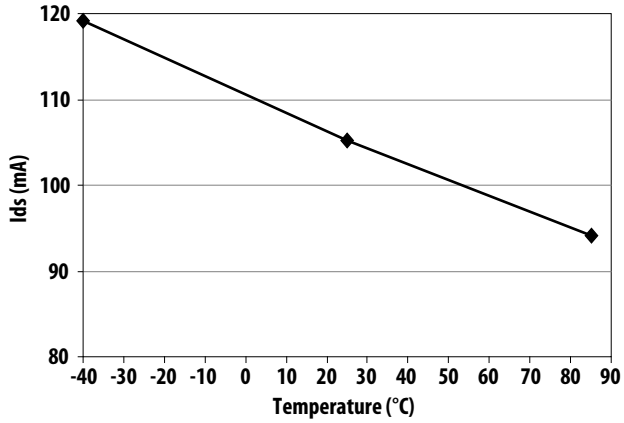


Figure 14. Ids over Temperature

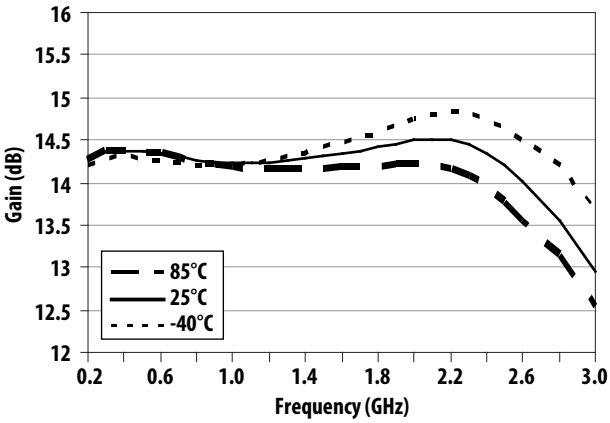


Figure 15. Gain over Frequency and Temperature

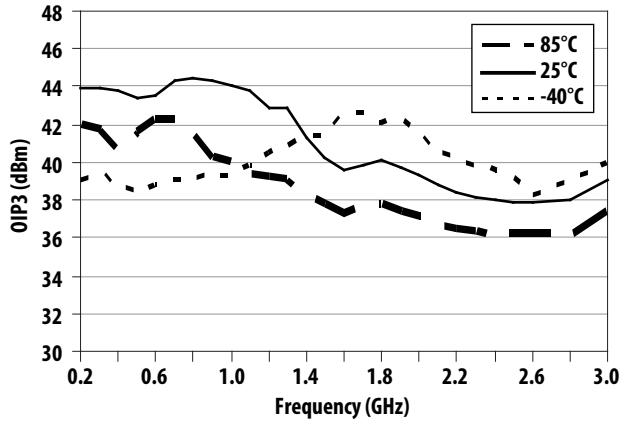


Figure 16. OIP3 over Frequency and Temperature

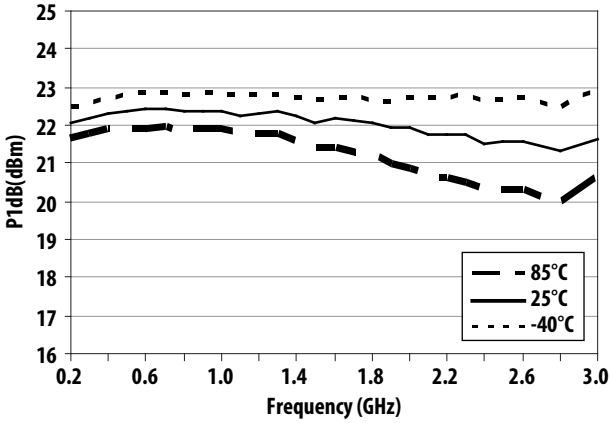


Figure 17. P1dB over Frequency and Temperature

Typical Performance (0.2GHz – 3GHz)

TA = +25°C, Vdd = 5V, Input Signal = CW. Application Test Circuit is shown in Figure 30 and Table 2.

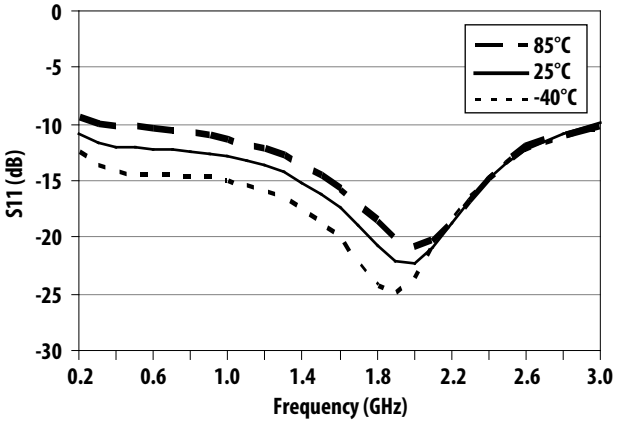


Figure 18. S11 over Frequency and Temperature

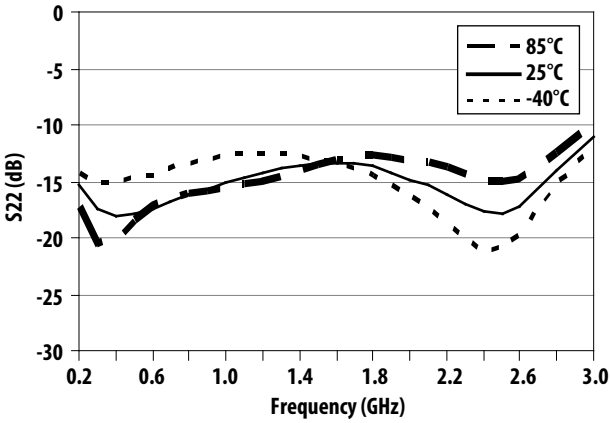


Figure 19. S22 over Frequency and Temperature

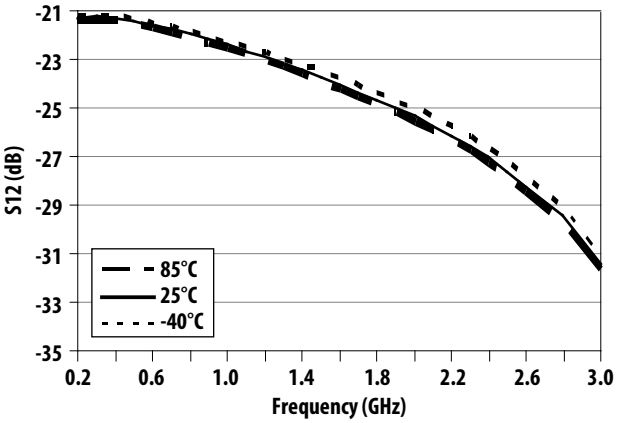


Figure 20. S12 over Frequency and Temperature

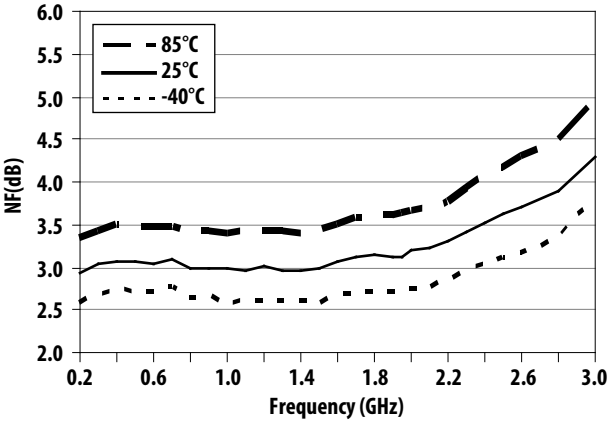


Figure 21. Noise Figure over Frequency and Temperature

Typical Performance (1.5GHz – 2.6GHz)

TA = +25°C, Vdd = 5V, Input Signal = CW. Application Test Circuit is shown in Figure 30 and Table 3.

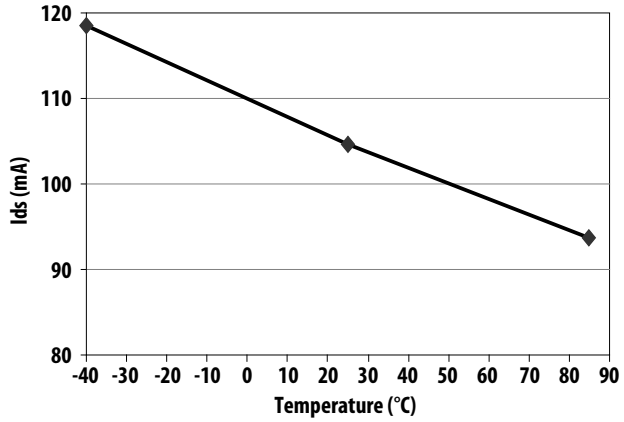


Figure 22. Ids over Temperature

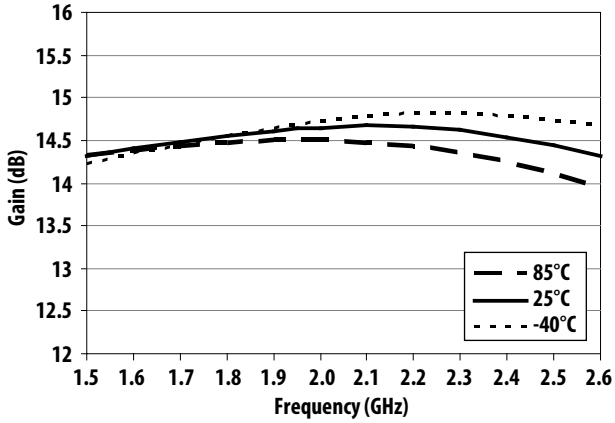


Figure 23. Gain over Frequency and Temperature

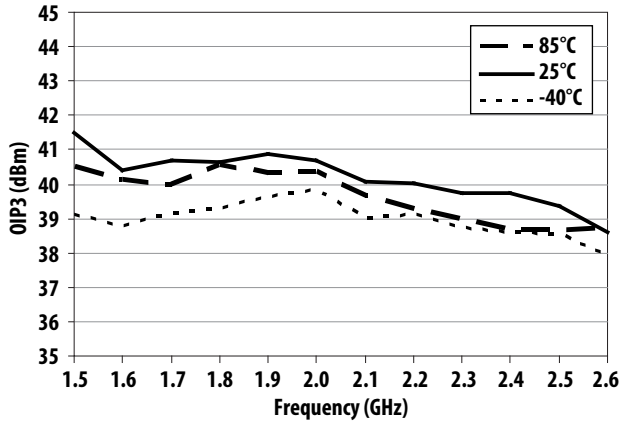


Figure 24. OIP3 over Frequency and Temperature

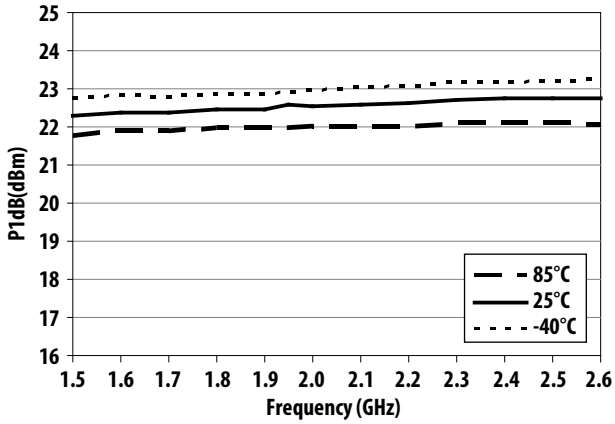


Figure 25. P1dB over Frequency and Temperature

Typical Performance (1.5GHz – 2.6GHz)

TA = +25°C, Vdd = 5V, Input Signal = CW. Application Test Circuit is shown in Figure 30 and Table 3.

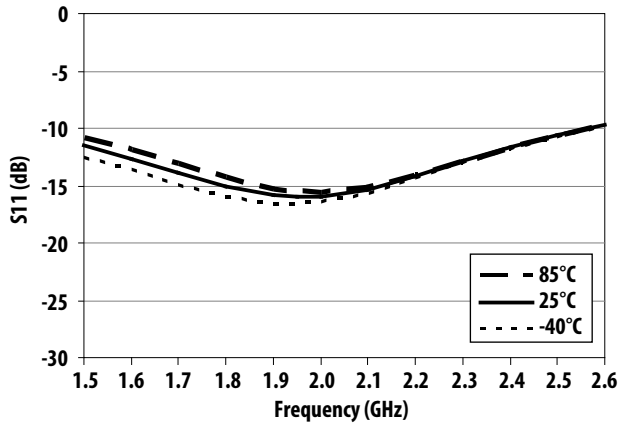


Figure 26. S11 over Frequency and Temperature

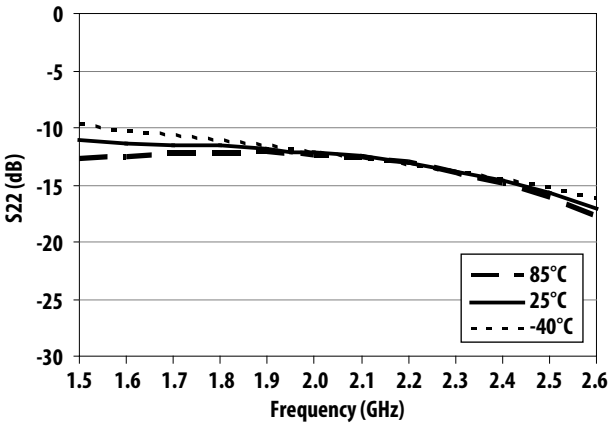


Figure 27. S22 over Frequency and Temperature

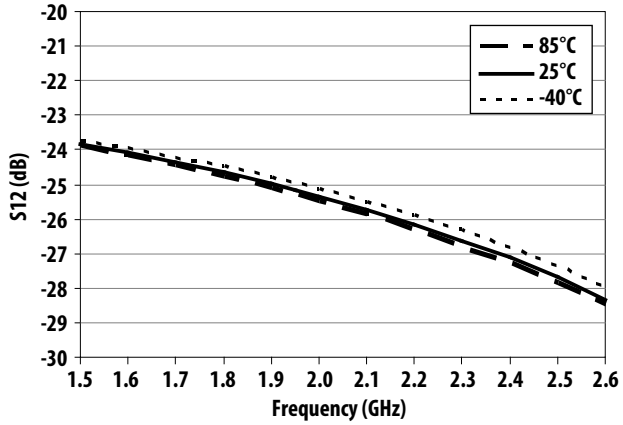


Figure 28. S12 over Frequency and Temperature

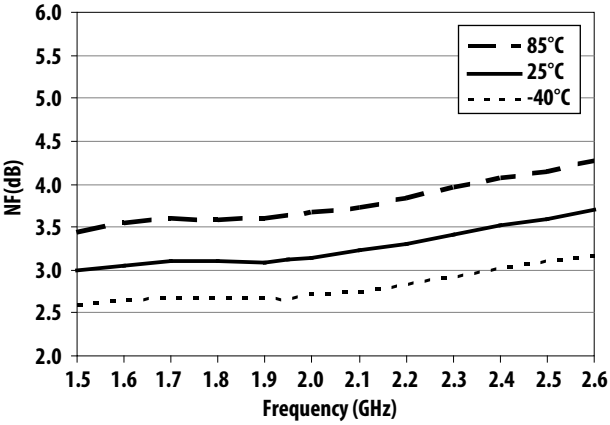


Figure 29. Noise Figure over Frequency and Temperature

Application Schematic Components Table and Demo Board

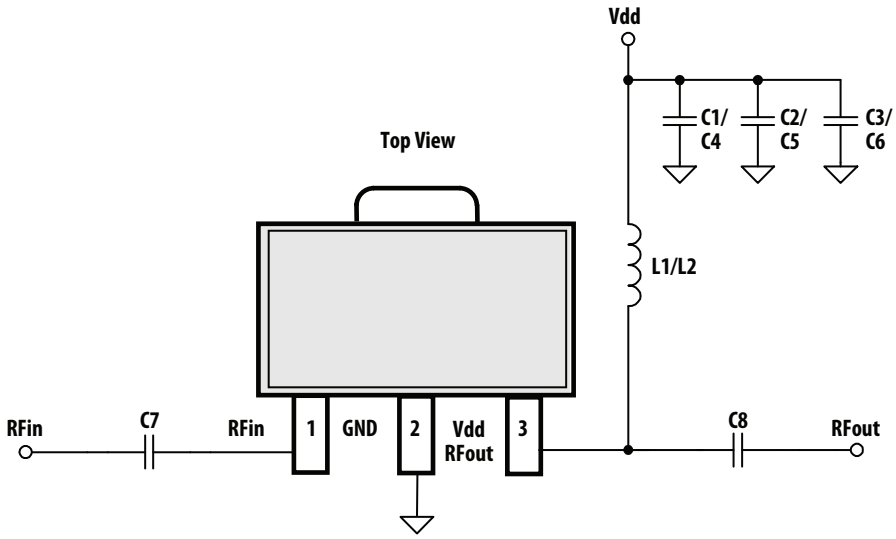
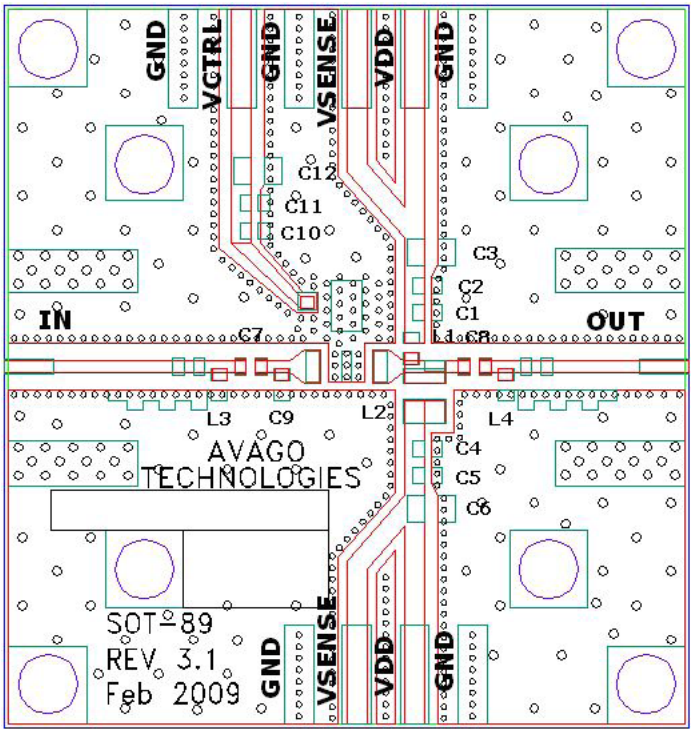


Figure 30. Application Schematic



– Recommended PCB material is 10 mils Rogers RO4350, with FR4 backing for mechanical strength.

– Suggested component values may vary according to layout and PCB material.

Figure 31. Demo board Layout

Demo board Part List

Table 1. 40 MHz – 2 GHz Application Schematic Components

Circuit Symbol	Size	Value	Part Number	Description
L2	0805	820nH	LLQ2012-series (Toko)	Wire Wound Chip Inductor
C4	0402	100pF	GRM1555C1H101JZ01B (Murata)	Ceramic Chip Capacitor
C5	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C6	0805	2.2uF	GRM21BR61E225KA12L (Murata)	Ceramic Chip Capacitor
C7	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C8	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor

Table 2. 0.2 GHz – 3 GHz Application Schematic Components

Circuit Symbol	Size	Value	Part Number	Description
L1	0402	100nH	LL1005-FHLR10J (Toko)	MLC Inductor
C1	0402	10pF	GRM1555C1H100JZ01B (Murata)	Ceramic Chip Capacitor
C2	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C3	0805	2.2uF	GRM21BR61E225KA12L (Murata)	Ceramic Chip Capacitor
C7	0402	100pF	GRM1555C1H101JZ01B (Murata)	Ceramic Chip Capacitor
C8	0402	100pF	GRM1555C1H101JZ01B (Murata)	Ceramic Chip Capacitor

Table 3. 1.5 GHz – 2.6 GHz Application Schematic Components

Circuit Symbol	Size	Value	Part Number	Description
L1	0402	5.6nH	LL1005-FHL5N6S (Toko)	MLC Inductor
C1	0402	100pF	GRM1555C1H101JZ01B (Murata)	Ceramic Chip Capacitor
C2	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C3	0805	2.2uF	GRM21BR61E225KA12L (Murata)	Ceramic Chip Capacitor
C7	0402	20pF	GRM1555C1H200JZ01B (Murata)	Ceramic Chip Capacitor
C8	0402	20pF	GRM1555C1H200JZ01B (Murata)	Ceramic Chip Capacitor

Test Circuit for S-Parameter and Noise Parameter

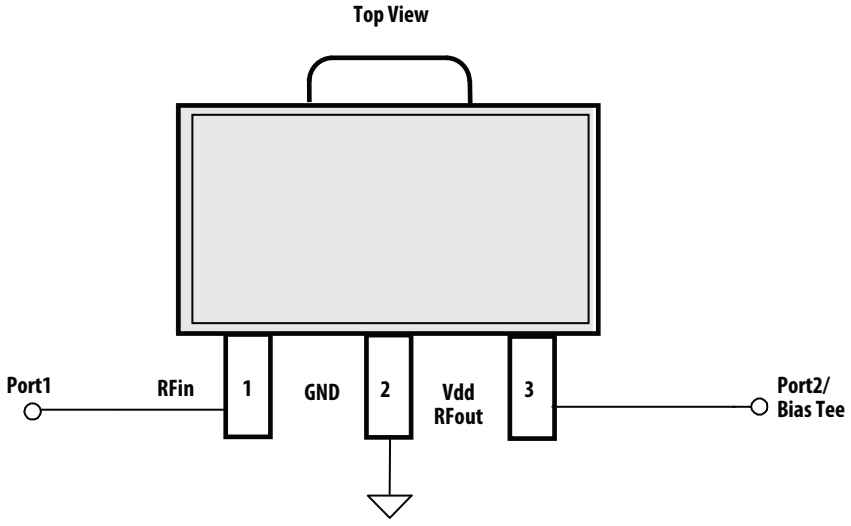


Figure 32. S-parameter and Noise parameter test circuit

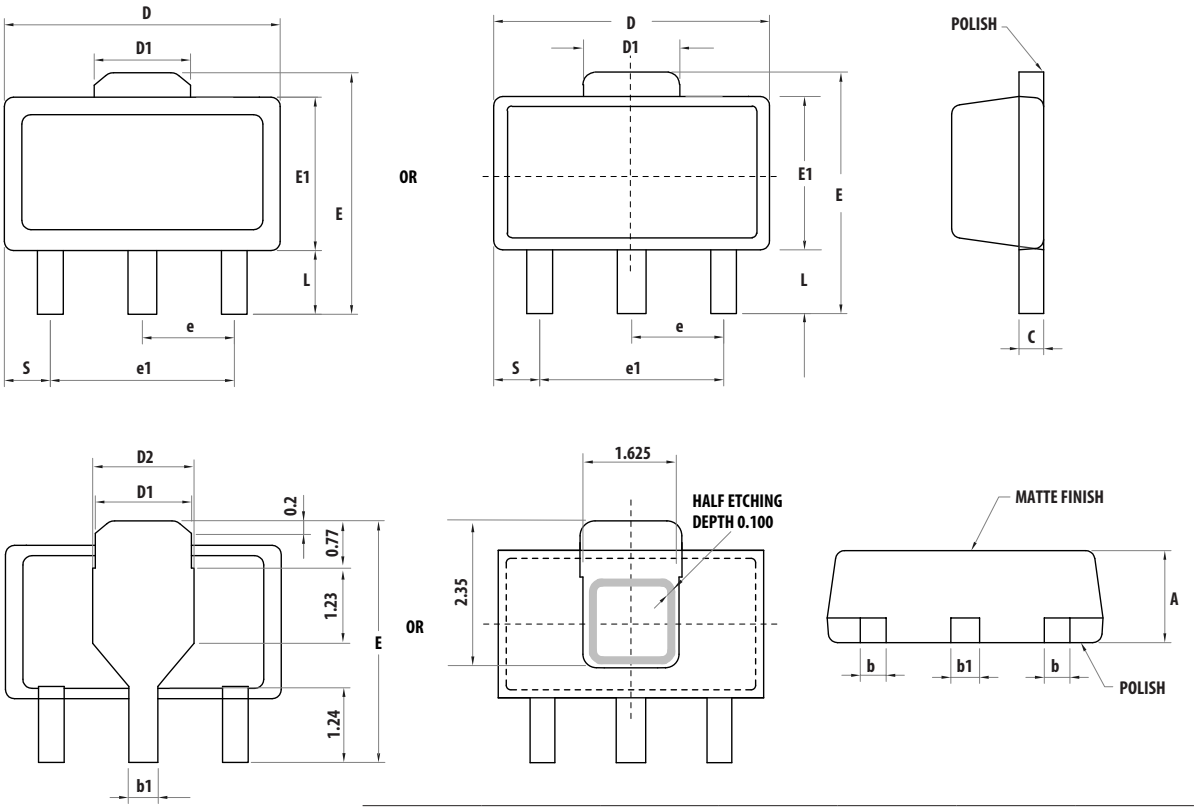
Typical S-Parameter (Vdd=5V, T=25°C, 50 ohm)

Freq (GHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
0.04	-12.99	-32.00	15.06	168.04	-20.92	5.28	-16.84	-127.51
0.1	-14.08	-27.40	14.79	169.90	-20.96	-2.48	-19.24	-154.22
0.2	-14.01	-38.85	14.76	165.35	-21.03	-8.75	-19.58	-162.15
0.3	-13.91	-53.66	14.74	159.56	-21.12	-14.11	-19.26	-164.02
0.4	-13.77	-68.63	14.73	153.53	-21.22	-19.09	-18.74	-163.03
0.5	-13.35	-83.56	14.73	147.37	-21.33	-23.96	-18.11	-160.98
0.6	-13.00	-97.71	14.73	141.14	-21.47	-28.71	-17.39	-160.35
0.7	-12.72	-111.41	14.73	134.86	-21.62	-33.44	-16.68	-161.36
0.8	-12.52	-124.63	14.74	128.51	-21.80	-38.09	-16.06	-163.41
0.9	-12.39	-137.62	14.76	122.08	-22.00	-42.67	-15.52	-166.34
1	-12.34	-150.05	14.78	115.62	-22.22	-47.13	-15.24	-169.82
1.1	-12.41	-161.87	14.82	109.17	-22.44	-51.53	-15.28	-173.97
1.2	-12.54	-175.41	14.84	102.50	-22.70	-55.82	-14.89	-179.03
1.3	-12.69	170.65	14.85	95.82	-22.99	-60.06	-14.57	175.40
1.4	-12.82	156.26	14.87	89.03	-23.31	-64.12	-14.31	169.62
1.5	-12.93	141.66	14.88	82.19	-23.64	-68.01	-14.12	163.81
1.6	-13.01	126.78	14.89	75.26	-23.99	-71.72	-14.00	157.96
1.7	-13.03	111.68	14.90	68.25	-24.35	-75.22	-13.93	152.01
1.8	-13.01	96.50	14.90	61.16	-24.71	-78.44	-13.94	146.11
1.9	-12.95	81.20	14.90	53.95	-25.07	-81.61	-14.00	140.34
2	-12.88	65.77	14.90	46.65	-25.43	-84.49	-14.15	134.63
2.1	-12.81	50.14	14.89	39.20	-25.77	-87.34	-14.40	129.04
2.2	-12.70	34.17	14.87	31.61	-26.12	-90.10	-14.76	123.74
2.3	-12.58	17.76	14.83	23.90	-26.47	-92.75	-15.29	118.58
2.4	-12.41	0.95	14.78	16.00	-26.81	-95.33	-16.00	113.77
2.5	-12.16	-16.14	14.71	7.96	-27.17	-98.00	-16.96	109.37
2.6	-11.80	-33.20	14.61	-0.24	-27.55	-100.74	-18.30	105.50
2.7	-11.33	-49.82	14.49	-8.55	-28.00	-103.33	-20.25	102.35
2.8	-10.76	-65.59	14.34	-17.05	-28.53	-105.61	-23.31	101.97
2.9	-10.13	-80.17	14.15	-25.68	-29.14	-107.36	-28.97	113.12
3	-9.48	-93.20	13.93	-34.41	-29.83	-107.91	-32.62	-162.21
4	-4.21	-168.28	7.93	-120.56	-27.04	-106.92	-5.05	172.01
5	-3.59	147.25	0.81	-166.87	-26.54	-152.31	-5.03	119.44
6	-3.85	96.49	-4.08	149.56	-27.32	163.02	-5.99	64.27
7	-2.69	44.14	-9.83	107.31	-29.75	120.51	-4.59	18.14
8	-1.77	16.03	-14.96	78.14	-31.67	91.43	-3.79	-4.64
9	-1.75	-9.43	-17.88	50.07	-31.40	63.78	-4.06	-28.88
10	-1.78	-50.02	-20.61	13.00	-31.03	27.56	-3.96	-68.59
11	-1.13	-83.66	-24.77	-17.84	-32.33	-2.54	-2.84	-99.28
12	-0.68	-93.53	-27.85	-31.54	-32.97	-16.55	-2.41	-112.27
13	-0.60	-96.96	-28.26	-42.20	-31.56	-29.12	-3.06	-124.68
14	-0.75	-111.43	-27.18	-66.26	-29.27	-55.40	-5.12	-151.90
15	-0.78	-137.85	-27.02	-107.10	-28.39	-98.30	-10.11	172.41
16	-0.60	-158.35	-29.80	-158.40	-30.72	-150.20	-13.09	-114.20
17	-0.46	-169.66	-36.11	159.22	-36.78	166.86	-4.23	-127.84
18	-0.46	-177.82	-41.41	126.91	-42.05	133.28	-2.40	-147.29
19	-0.56	173.41	-43.20	81.20	-44.00	83.71	-2.16	-162.89
20	-0.76	158.69	-40.61	50.84	-41.28	51.14	-2.26	-173.39

Typical Noise Parameters (Vdd=5V, T=25°C, 50 ohm)

Freq (GHz)	Fmin (dB)	Γ_{opt} Mag	Γ_{opt} Ang	Rn/Z0
0.4	3.04	0.203	13.20	0.522
0.9	2.80	0.205	14.50	0.466
1.0	2.87	0.208	16.30	0.468
1.7	2.82	0.211	19.80	0.496
1.85	2.81	0.214	20.80	0.512
2.0	2.83	0.217	26.10	0.526
2.5	3.05	0.280	51.60	0.59
3.0	3.84	0.356	95.30	0.596
3.5	4.27	0.468	142.00	0.362
4.0	5.18	0.537	174.50	0.234
4.5	5.20	0.522	-163.90	0.29
5.0	6.16	0.534	-142.24	0.618

SOT89 Package Dimensions

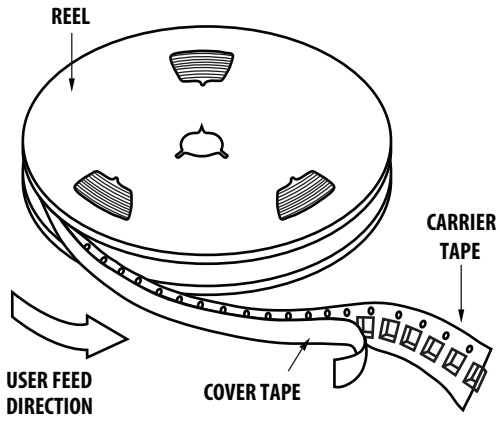


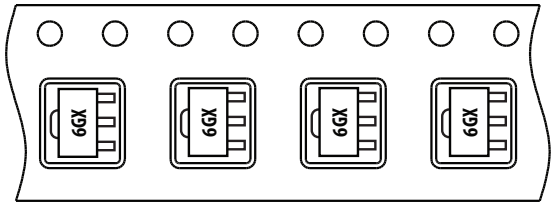
	Dimensions in mm			Dimensions in inches		
Symbols	**Minimum**	**Nominal**	**Maximum**	**Minimum**	**Nominal**	**Maximum**
A	1.40	1.50	1.60	0.055	0.059	0.063
L	0.89	1.04	1.20	0.0350	0.041	0.047
b	0.36	0.42	0.48	0.014	0.016	0.018
b1	0.41	0.47	0.53	0.016	0.018	0.030
C	0.38	0.40	0.43	0.014	0.015	0.017
D	4.40	4.50	4.60	0.173	0.177	0.181
D1	1.40	1.60	1.75	0.055	0.062	0.069
D2	1.45	1.65	1.80	0.055	0.062	0.069
E	3.94	-	4.25	0.155	-	0.167
E1	2.40	2.50	2.60	0.094	0.098	0.102
e1	2.90	3.00	3.10	0.114	0.118	0.122
S	0.65	0.75	0.85	0.026	0.030	0.034
e	1.40	1.50	1.60	0.054	0.059	0.063

Part Number Ordering Information

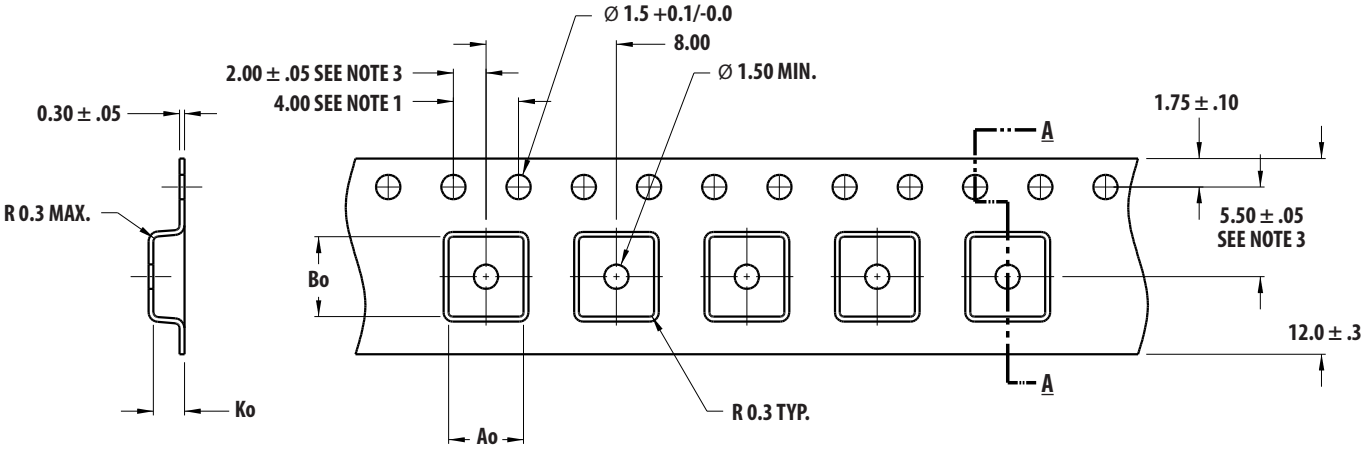
Part Number	No. of Devices	Container
MGA-30689-BLKG	100	7″ Tape/Reel
MGA-30689-TR1G	3000	13″ Tape/Reel

Device Orientation





Tape Dimensions



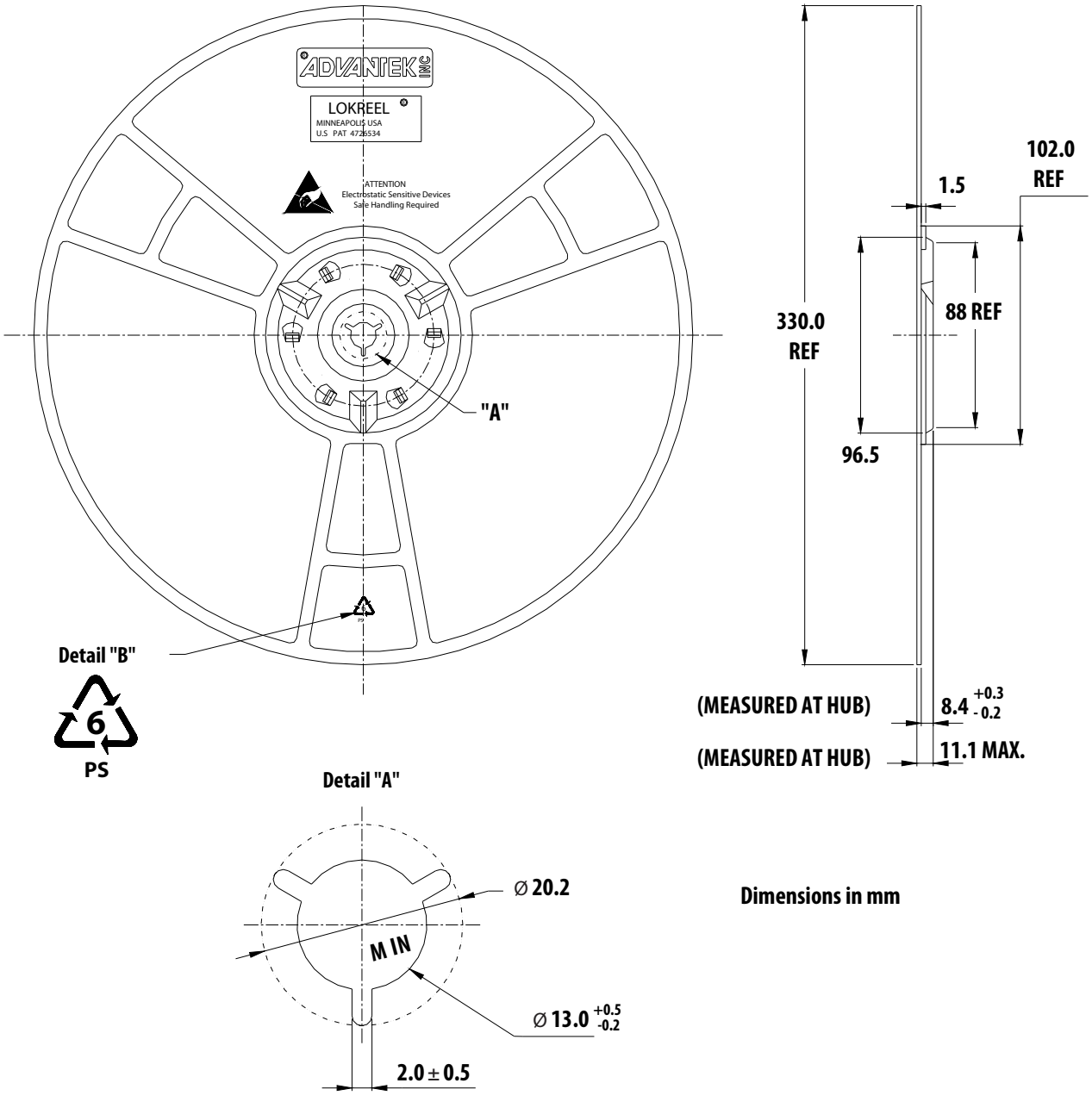
SECTION A - A

Ao = 4.60
Bo = 4.90
Ko = 1.90

DIMENSIONS IN MM

NOTES:
1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.2
2. CAMBER IN COMPLIANCE WITH EIA 481
3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE

Reel Dimensions – 13″ Reel



Dimensions in mm

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